

AMENDMENTS TO THE SPECIFICATION:

Please add the following new paragraph on page 1, after the title of the invention and before the “Background of the Invention”:

This application is a Divisional application of Application No. 10/055,999, filed January 28, 2002, which is hereby incorporated by reference and claims priority to Patent Application Number 2001-5065 filed in Rep. of Korea on February 2, 2001, herein incorporated by reference.

Please replace the paragraph on page 8, beginning on line 12, with the following amended paragraph:

Preferred shapes of the laser output window 48b are shown in FIGS. 4 and 5. FIG. 4 shows the relation between the radius (R) of curvature of the laser output window 49b 48b, the radius (W) of the laser mode on the surface of the laser output window 48 48b, the radius (W₀) of the laser mode in the active layer 40, and the thickness (Z) of the spacer 48. In FIG. 5, graphs G1 and G2 show variation in the radius (W) of the laser mode on the surface of the laser output window 48b and the radius (R) of curvature of the laser output window 48b with respect to thickness (Z) of the spacer 48. As shown in FIG. 5, the radius (W) of the laser mode on the surface of the laser output window 48b becomes smaller with reduced thickness (Z) of the spacer 48, and the radius (R) of curvature of the laser output window 48b is the smallest at a spacer thickness (Z) in the range of 200-250 μm . The spacer thickness (Z) and the radius (R) of curvature of the laser output window 48b, at which the radius (W₀) of the laser mode in the active layer 40 becomes least, can be calculated with reference FIGS. 4 and 5.